

Effect of Iodine Doping on $\text{Bi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_x$: Charge Transfer or Interlayer Coupling?

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Abstract

A comparative study has been made of iodine-intercalated $\text{Bi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_x$ single crystal and 1 atm O_2 annealed $\text{Bi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_1\text{O}_x$ single crystal using AC susceptibility measurement, X-ray photoemission (XPS) and angle-resolved ultraviolet photoemission spectroscopy (ARUPS). AC susceptibility measurement indicates that O_2 -doped samples studied have T_c of 84 °K, whereas T_c of Iodine-doped samples studied are 80 °K. XPS Cu 2p core level data establish that the hole concentration in the CuO_2 planes are essentially the same for these two kinds of samples. ARUPS measurements show that electronic structure of the normal states near the Fermi level has been strongly affected by iodine intercalation. We conclude that the dominant effect of iodine doping is to alter the interlayer coupling.

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The normal state properties of high T_c cuprate superconductors continues to be of much interest since probing the nature of the normal state may provide the key to understanding the mechanism of high- T_c superconductivity. [1] Since the report that iodine has been successfully intercalated between BiO bilayers of the $\text{Bi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_x$, [2] many studies have been made of its crystal structure, [2–4,6,7] transport properties [3,5,8,11] and electronic properties. [10–12] A key unanswered question is how iodine intercalation alters the superconducting properties of intercalated $\text{Bi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_x$. By using transmission electron microscopy(TEM) and X-ray diffraction, Xiang et al [3,8] concluded that iodine is epitaxially intercalated between the Bi-O bilayers with CuO_2 planes unaffected. They found that metallic CuO_2 planes in the normal state above T_c are unaffected by the intercalation; however, the c-axis electrical resistivity is changed from semiconducting to metallic-like behavior. They attributed the reduction of T_c for $\text{IBi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_x$ to the change of interlayer coupling, but did not rule out a smaller effect on T_c due to charge transfer from the iodine layers to the CuO_2 layers. By contrast, based on X-ray photoemission(XPS) and Hall coefficient measurements, Pooke et al [11] and Choy et al [12] concluded that the dominant cause of changes in T_c is charge transfer from the iodine to the CuO_2 planes. Whether T_c is controlled by in-plane carrier density or by interlayer coupling has been an important issue for a long time in the high T_c superconductivity community. [13] Our approach is to perform a comprehensive and comparative study of iodine-intercalated Bi-2212 and 1 atm O_2 annealed Bi-2212. We concluded that it is the change of interlayer coupling due to the iodine intercalation that dominates the change of T_c between the two kinds of samples that have been studied. Using synchrotron radiation angle-resolved photoemission, we found that the electronic structure along one of the main symmetry directions, specifically Γ -X(corresponding to the Bi-O bond axis in real space), has been strongly affected by this change of interlayer coupling associated with iodine intercalation.

The stage one $\text{IBi}_2\text{Sr}_2\text{Ca}_1\text{Cu}_2\text{O}_x$ samples were prepared using the method reported by Xiang et al. [2,3,8] The samples were characterized by X-ray diffraction, micro-probe (Cameca CAMEBAX SX-50) and resistivity measurements.

The AC susceptibility measurements were obtained using a Lakeshore 7000 series susceptometer/magnetometer. The temperature step size has been chosen so that the determination of T_c was accurate to 0.2 K.

The X-ray photoemission spectroscopy(XPS) measurements were performed in Lausanne Centre de Spectromicroscopie, Switzerland, using the SCIENTA ESCA-300 system which is equipped with a rotating anode Al $K\alpha$ radiation source, a seven-quartz-crystal monochromator and a concentric hemispherical analyser. The overall energy resolution of the system for this measurement was 340 meV. The chamber pressure during the measurement was 2×10^{-10} torr.

The angle-resolved ultraviolet photoemission measurements were conducted using the four meter normal incidence monochromator at the Synchrotron Radiation Center in Wisconsin, and a Vacuum Science Workshop hemispherical angle-resolved analyser which has an acceptance full angle of two degrees. The experiment was performed at room temperature. The energy resolution of 140 meV was determined by measuring the Fermi edge of a gold film. The nominal chamber pressure during the measurement was 1.7×10^{-10} torr.

In both XPS and ARUPS measurements, the samples were placed in a load lock chamber with a base pressure lower than 5×10^{-9} torr, transferred into the main chamber, and cleaved under an ultra-high vacuum of 2×10^{-10} . In this way we made certain that both iodine-doped samples and O_2 annealed samples retained their original stoichiometries.

We confirmed the sample orientation using low energy electron diffraction. Our measurements along Γ -X in reciprocal space correspond to the Bi-O bond axis direction in real space, while the Γ -M direction in reciprocal space corresponds to the Cu-O-Cu bond axis direction in real space.

In order to separate the effects of charge transfer and interlayer coupling, we carefully altered the oxygen stoichiometry so that the $Cu^{+1}:Cu^{+2}$ ratio obtained from XPS data was the same for the two types of samples. By doing so, we intended to determine the effects of interlayer coupling, without differences in charge transfer complicating the interpretation.

Fig. 1 illustrates Cu $2p_{3/2}$ XPS core-level spectra for the B-2212 single crystals with 1

atm O₂ annealing at 650 °C for 16 hours(a) and with iodine intercalation(b). We used one atmosphere O₂ annealing to obtain as closely as possible the same carrier density for samples with and without iodine intercalation. From the spectrum one can observe a main peak at about 933 eV corresponding to the well-screened core hole final state of the 2p⁵3d¹⁰L, where L indicates a hole on the ligand oxygen, and a weak broad satellite centered at about 945 eV corresponding to a poorly-screened final state of the 2p⁵3d⁹ configuration. We deconvoluted the main peak into three components. The two lower binding energy components comprise the Cu⁺¹. The satellite and the rest of higher binding energy components comprise Cu⁺². [14,10] Using this, the ratio of Cu⁺¹:Cu⁺² for two kinds of samples are found to be 0.87 ± 0.03 for I-doped sample and 0.92 ± 0.03 for O₂ annealed sample. These ratios are the same within experimental accuracy. The data indicates the carrier density in CuO₂ planes are the same for the I-doped sample and O₂ annealed sample.

Fig. 2 illustrates the AC susceptibility of a Bi 2:2:1:2 single crystal after 16 hours 1 atm O₂ annealing at 650 °C and that of Bi 2:2:1:2 single crystal after iodine intercalation. The onset T_c is 84 °K for O₂ annealed sample and 80 °K for the iodine-intercalated sample. The T_c of our as-grown samples is 90 °K. It is clear that there is a difference of 4 °K in their transition temperatures for 1 atm O₂ annealed sample and I-doped sample.

Bi 5d_{3/2} and 5d_{5/2} spectra for Bi-2212 with O₂ annealing and with iodine intercalation are shown in Fig. 3. We determined that the Bi 5d_{3/2} and Bi 5d_{5/2} levels have the same binding energies, 28.7 eV and 25.7 eV, respectively for the two kinds of samples. These results are consistent with Cu 2p_{3/2} data, because we would expect no shift of corresponding core level binding energies since there is no difference in hole doping.

The above XPS Cu(2p) core level spectra, AC susceptibility data, Bi(5d) core level spectra establish that the difference in T_c between the two types of samples studied cannot be explained in terms of differences in hole concentration.

Xiang et al [8] interpreted the observed change in T_c using two models: the Wheatley-Hsu-Anderson(WHA) model [15] and, as they modified in Ref.9, the Ihm-Yu model. [16] They found that the depression of T_c can be understood if one assumes that the next-nearest

CuO₂ plane coupling is essentially eliminated by iodine intercalation; therefore, the interlayer hopping matrix element for the next-nearest-neighbor CuO₂ planes is greatly reduced. Such an interpretation is consistent with high pressure experiments that report $dT_c/dP > 0$. [17] We studied whether there was any indication of change of interlayer coupling from the point of view of electronic structure. Specifically, we measured the band structure. The spectra illustrated in Fig. 4 were taken along the Γ -X direction using a photon energy of 21 eV. For the iodine-intercalated sample Fig. 4, we observe a band dispersing towards the Fermi level from 160 meV below E_f at θ of 10 degrees. The band crosses the Fermi level at $\theta = 16$ degree and remains at the Fermi level for another two degrees. After crossing the Fermi level, the trailing edge of this band is still visible for θ as large as 22 degrees. By contrast, for an oxygen annealed sample, the band crosses the Fermi level at $\theta = 12$ degree. [18,19] The experimental dispersion relations for both iodine doped and O₂ annealed samples are shown in Fig. 5. The amount of dispersion is quite different for two types of samples. The iodine intercalated samples exhibit a reduced dispersion, which is about 1.7 times less than that of the oxygen annealed sample, and a larger Fermi wave vector. Band structure calculations suggest that this band is mostly of CuO character. [20] The data indicate that the change of interlayer coupling has altered band structure in the Γ -X direction.

We performed similar measurements in the Γ -M direction. We found no significant difference in the dispersion or Fermi wave vector between samples.

In summary, our comparative study of iodine-intercalated Bi-2212 single crystal and O₂ annealed Bi-2212 has found that the T_c is significantly affected by interlayer coupling effects rather than solely by hole carrier concentrations. Our data have established that the electronic structure of the normal state is dependent on the strength of the interlayer coupling.

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FIGURES

FIG. 1. The Cu($2p_{3/2}$) XPS core level spectra for iodine-intercalated Bi-2212 single crystal(a), and for 1 atm O₂ annealed Bi-2212(b).

FIG. 2. The AC susceptibility data for iodine-intercalated Bi-2212 single crystal(a) and the data for 1 atm O₂ annealed Bi-2212(b). The onset T_c's are 80 °K and 84 °K, respectively.

FIG. 3. The Bi(5d) UPS core level spectra for iodine-intercalated Bi-2212 single crystal(a), and for 1 atm O₂ annealed Bi-2212(b).

FIG. 4. The angle-resolved photoemission spectra of iodine-intercalated Bi-2212 taken at room temperature along the Γ -X directions. The photon energy $h\nu$ is 21 eV.

FIG. 5. The dispersion relations of the same band along Γ -X for iodine-intercalated Bi-2212(a), and for 1 atm O₂ annealed Bi-2212(b). Both curves are experimental ones.